



Atty Docket No.: TKHR4540

Serial No.: 09/467,675

H20/D

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of : *3/12/03*
Application No. : 09/467,675
Filed : December 21, 1999
For : Structure For ESD Protection With Single Crystal Silicon Sided Junction
Applicant : Liou et al.
Examiner : Ori Nadav
Art Unit : 2811

AMENDMENT AND RESPONSE TO OFFICE ACTION

Assistant Commissioner of Patents and Trademarks
Washington, DC 20231

Sir:

In response to the Office Action dated September 30, 2002, please consider the following remarks.

In The Claims:

Please substitute the following clean text claims for the pending claims having the same number.

SAC 21
1. (Thrice Amended) An ESD protection structure having a single crystal Si-sided diode used to protect an internal circuit, the ESD protection structure electrically connected between an input pad and a node and the internal circuit electrically connected to the node, the ESD protection structure comprising:
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